

#### **Spread Spectrum Clock Generator for Mobile Applications**

#### **Features**

- Generates a 4X EMI optimized clock signal at the Output.
- Input frequency : 12.5MHz to 20MHz
- Output frequency: 50MHz to 80MHz
- · REFOUT is same as input frequency
- Selectable Centre Spread : ± 0.5%, ± 1.0%
- · Low power CMOS design
- 3.3V ± 0.3V Operating Voltage
- Available in Industrial Temperature range (-40to 85°C)
- Available in 8-pin TSSOP
- Drop-in replacement for MB88155-412 Device

#### **Product Description**

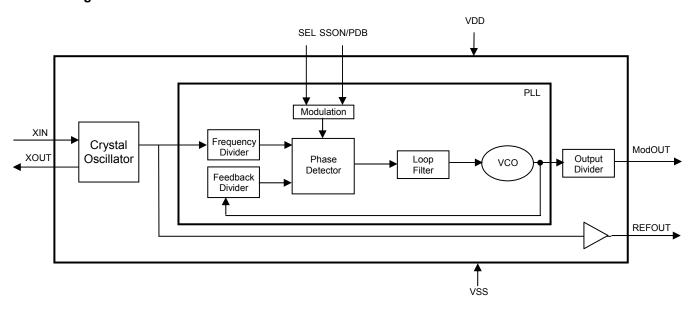
The ASM3P2187A/B is a versatile spread spectrum frequency modulator designed specifically for a wide range of clock frequencies. The ASM3P2187A/B reduces electromagnetic interference (EMI) at the clock source, allowing system wide reduction of EMI of all clock dependent signals. The ASM3P2187A/B allows significant system cost savings by reducing the number of circuit board layers ferrite beads, shielding that are traditionally required to pass EMI regulations.

ASM3P2187A device has an option of Spread ON/OFF and ASM3P2187B device has Powerdown option

#### **Applications**

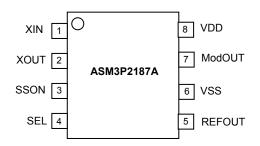
The ASM3P2187A/B is targeted towards mobile phones, mobile audio players and PDAs.

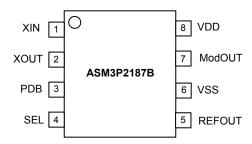
#### **Block Diagram**





#### **Pin Configurations**





#### **Pin Description**

Pin#	Pin Name	Туре	Description		
1	XIN	I	Crystal connection or external reference frequency input. This pin has dua functions. It can be connected either to an external crystal or an external reference clock.		
2	XOUT	0	Crystal connection. If using an external reference, this pin must be left unconnected.		
3	SSON / PDB*	I	Modulation enable pin/ Power down pin. Has an Internal pull up resistor		
4	SEL	I	Modulation rate setting pin Centre spread, SEL = "L": Frequency Deviation ± 0.5% Centre spread, SEL = "H": Frequency Deviation ± 1.0% Has an Internal pull up resistor.		
5	REFOUT	0	Non-modulated clock output pin. The Frequency is same as input frequency. This pin becomes to "L" at power-down.		
6	VSS	Р	Ground Connection. Connect to system ground.		
7	ModOUT	0	Modulated clock output pin This pin becomes to "L" at power-down.		
8	VDD	Р	Power Supply Voltage Pin. Connect to +3.3V.		

<sup>\*</sup> SSON Pin is available in ASM3P2187A Device and PDB Pin is available in ASM3P2187B Device



# **Modulation Enable Setting Table**

SSON	Modulation
L	No Modulation
Н	Modulation

#### **Power down Status Table**

PDB	Status	
L	Power Down Status	
Н	Operating Status	

# **Spread Range Selection Table**

SEL	Spreading Range		
L	± 0.50%		
Н	± 1.00%		

#### **Absolute Maximum Ratings**

Symbol	Parameter	Rating	Unit		
VDD	Supply Voltage pin with respect to Ground	-0.5 to +4.6	V		
V <sub>IN</sub>	Input Voltage pin with respect to Ground	VSS-0.5 to VSS+0.5	V		
V <sub>OUT</sub>	Output Voltage pin with respect to Ground	VSS-0.5 to VSS+0.5	V		
T <sub>STG</sub>	Storage temperature	-55 to +125	°C		
T <sub>A</sub>	Operating temperature	-40 to +85	°C		
Ts	Max. Soldering Temperature (10 sec)	260	°C		
TJ	Junction Temperature	-40 to +125	°C		
T <sub>DV</sub> Static Discharge Voltage (As per JEDEC STD22- A114-B)			KV		
Note: These are stress ratings only and are not implied for functional use. Exposure to absolute maximum ratings for prolonged periods of time may affect					



# June 2006 Giving you the edge ASM3P2187A/B

rev 0.1

#### **DC Electrical Characteristics**

( Test condition: All parameters are measured at -40°C to +85°C,  $3.3V \pm 0.3V$ , VSS =0V , unless otherwise stated)

Symbol	Parameter			Min	Тур	Max	Unit	
V <sub>IL</sub>	Input low voltage			VSS - 0.3	-	0.8	V	
V <sub>IH</sub>	Input high voltage			2.0	-	VDD+ 0.3	V	
I <sub>IL</sub>	Input low current			-	-	-35	μΑ	
I <sub>IH</sub>	Input high current			-	-	+35	μΑ	
I <sub>XOL</sub>	X <sub>OUT</sub> output low currer	nt ( V <sub>XOL</sub> @ 0	.4V, VDD = 3.3V)	-	3	-	mA	
I <sub>XOH</sub>	X <sub>OUT</sub> output high curre	nt (V <sub>XOH</sub> @	2.5V, VDD = 3.3V)	-	3	-	mA	
V <sub>OL</sub>	Output low voltage	For REFO	UT, I <sub>OL</sub> = 4mA UT, I <sub>OL</sub> = 3mA	VSS	-	0.4	V	
V <sub>OH</sub>	Output high voltage		UT, I <sub>OH</sub> = -4mA UT, I <sub>OH</sub> = -3mA	VDD-0.5	-	VDD	V	
Icc	Dynamic supply current , TBD MHz Output, no load				TBD	TBD	mA	
I <sub>DD</sub>	Static supply current standby mode				TBD		uA	
VDD	Operating voltage			3.3	3.3	3.6	V	
t <sub>ON</sub>	Power up time (first locked clock cycle after power up)			-	2	5	mS	
7	Clock output	For ModO	UT	-	TBD	-	Ω	
Z <sub>out</sub>	impedance	For REFOUT		-	TBD	-	Ω	
C <sub>IN</sub>	Input Capacitance, Ta=25°C, VDD=VIN=0V, f=1MHz			-	-	16	pF	
	Load Capacitance	REFOUT	12.5MHz to 50MHz	-	-	15		
$C_L$		ModOLIT	12.5MHz to 50MHz	-	-	15	pF	
	ModOUT		50MHz to 80MHz	-	-	7		

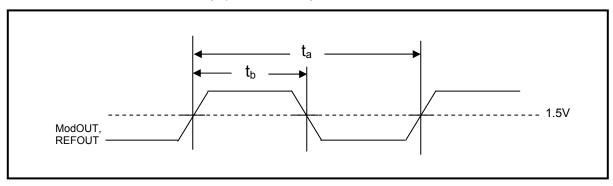
#### **AC Electrical Characteristics**

( Test condition: All parameters are measured at -40°C to +85°C,  $3.3V \pm 0.3V$ , VSS =0V , unless otherwise stated)

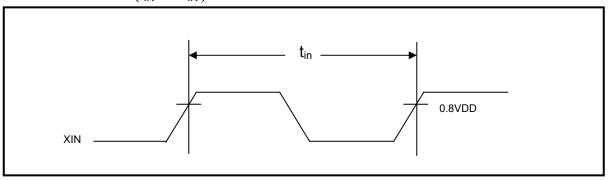
Symbol	Parameter		Min	Тур	Max	Unit
f <sub>IN</sub>	Input frequency	Input frequency		-	20	MHz
£	Output frequency	ModOUT	50	-	80	MHz
f <sub>OUT</sub>	Output frequency	REFOUT	12.5	-	20	IVITZ
t <sub>LH</sub> *	Output rise time ( Measu	Output rise time ( Measured from 0.8V to 2.0V )		TBD	-	nS
t <sub>HL</sub> *	Output fall time ( Measured from 2.0V to 0.8V )		-	TBD	-	nS
t <sub>JC</sub>	Jitter (Cycle to cycle), Ta=25°C and VDD=3.3V No Load Capacitance		-	-	TBD	pS
$t_D$	Output duty cycle	Output duty cycle		50	60	%
$M_F$	Modulation Frequency , Input Frequency =12.5M		32.4		KHz	



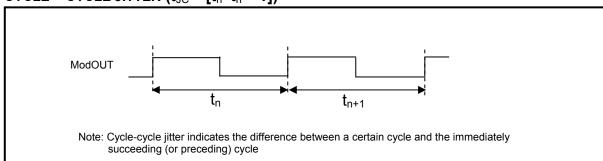
# OUT PUT CLOCK DUTY CYCLE ( $t_{D,}\ t_{DCR}$ = $t_b$ / $t_a$ )



# INPUT FREQUENCY ( $f_{IN} = 1/t_{IN}$ )

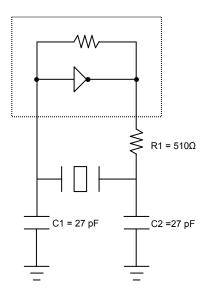


# CYCLE -- CYCLE JITTER $(t_{JC} = [t_n - t_n + 1])$





# **Typical Crystal Oscillator Circuit**



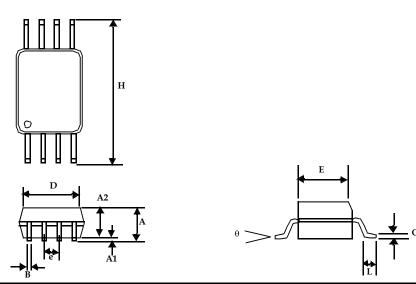
# **Typical Crystal Specifications**

Fundamental AT cut parallel resonant crystal				
Nominal frequency	14.31818MHz			
Frequency tolerance	± 50 ppm or better at 25°C			
Operating temperature range	-25°C to +85°C			
Storage temperature	-40°C to +85°C			
Load capacitance	18pF			
Shunt capacitance	7pF maximum			
ESR	25Ω			



# **Package Information**

# **Mechanical Package Outline 8-Pin TSSOP**



	Dimensions				
Symbol	Inc	hes	Millimeters		
	Min Max		Min	Max	
А		0.043		1.10	
A1	0.002	0.006	0.05	0.15	
A2	0.033	0.037	0.85	0.95	
В	0.008	0.012	0.19	0.30	
С	0.004	0.008	0.09	0.20	
D	0.114	0.122	2.90	3.10	
E	0.169	0.177	4.30	4.50	
е	0.026	BSC	0.65 BSC		
Н	0.252 BSC		6.40 BSC		
L	0.020	0.028	0.50	0.70	
θ	0°	8°	0°	8°	

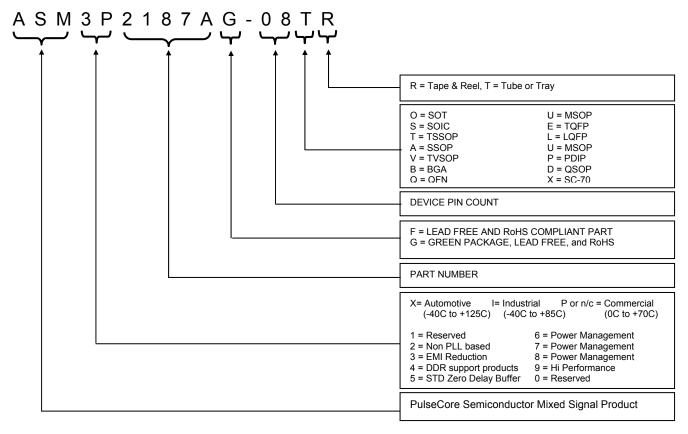
Note: Controlling dimensions are millimeters TSSOP – 0.034 grams unit weight



#### **Ordering Codes**

Part Number Marking		Package Type	Temperature
ASM3P2187AG-08TT	3P2187AG	8-Pin TSSOP, TUBE, Green	Commercial
ASM3P2187AG-08TR 3P2187AG		8-Pin TSSOP, TAPE & REEL, Green	Commercial
ASM3I2187AG-08TT	3I2187AG	8-Pin TSSOP, TUBE, Green	Industrial
ASM3I2187AG-08TR 3I2187AG		8-Pin TSSOP, TAPE & REEL, Green	Industrial
ASM3P2187BG-08TT	3P2187BG	8-Pin TSSOP, TUBE, Green	Commercial
ASM3P2187BG-08TR	3P2187BG	8-Pin TSSOP, TAPE & REEL, Green	Commercial
ASM3I2187BG-08TT	3I2187BG	8-Pin TSSOP, TUBE, Green	Industrial
ASM3I2187BG-08TR	3I2187BG	8-Pin TSSOP, TAPE & REEL, Green	Industrial

#### **Device Ordering Information**



Licensed under U.S Patent Nos 5,488,627 and 5,631,921







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 $Note: This \ product \ utilizes \ US \ Patent \ \# \ 6,646,463 \ Impedance \ Emulator \ Patent \ is sued \ to \ PulseCore \ Semiconductor, \ dated \ 11-11-2003 \ Additional \ Frank \ Additional \ Add$ 

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